Unit: mm

TOSHIBA Field-Effect Transistor Silicon P / N Channel MOS Type

# SSM6L13TU

**Power Management Switch Applications** 

**High-Speed Switching Applications** 

1.8-V drive

N-ch , P-ch 2-in-1

Low ON-resistance: Nch  $R_{DS(ON)} = 235 \text{ m}\Omega \text{ (max) } (@V_{GS} = 1.8 \text{ V})$ 

 $R_{DS(ON)} = 178 \text{ m}\Omega \text{ (max) } (@V_{GS} = 2.5 \text{ V})$ : Pch

 $R_{DS(ON)} = 460 \text{ m}\Omega \text{ (max) (@V_{GS} = -1.8 V)}$ 

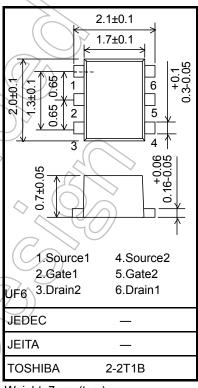
 $R_{DS(ON)} = 306 \text{ m}\Omega \text{ (max) (@V_{GS} = -2.5 V)}$ 

### Q1 Absolute Maximum Ratings (Ta = 25 °C)

				A11
Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DS}$	20	$(N \land$
Gate-source voltage		V <sub>GSS</sub>	±12	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Drain current	DC	I <sub>D</sub>	0.8	
	Pulse	I <sub>DP</sub>	1.6	*

## Q2 Absolute Maximum Ratings (Ta = 25 °C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V <sub>DS</sub>	-20	<_<
Gate-source voltage		V <sub>GSS</sub>	± 8	V
Drain current	DC	Þ	-0.8	^ ^
	Pulse	(DP	-1.6	A



Weight: 7 mg (typ.)

## Absolute Maximum Ratings (Q1, Q2 Common) (Ta = 25 °C)

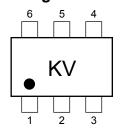
Characteristic	Symbol	Rating	Unit
Power dissipation	P <sub>D</sub> (Note 1)	500	mW
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

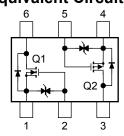
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board (total dissipation)  $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad: } 645 \text{ mm}^2)$ 

#### Marking



## **Equivalent Circuit (top view)**



Start of commercial production 2005-10

## Q1 Electrical Characteristics (Ta = 25°C)

Characte	eristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	20	_	_	V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	10	_	_	v
Drain cutoff current		I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0	1	_	1	μА
Gate leakage curre	nt	I <sub>GSS</sub>	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$		_	± 1	μА
Gate threshold volta	age	V <sub>th</sub>	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.4	))_	1.0	V
Forward transfer ad	Imittance	Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, I_D = 0.6 \text{ A}$ (Note 2)	2:3	3.75	_	S
Drain-source ON-resistance			$I_D = 0.6 \text{ A}, V_{GS} = 4.0 \text{ V}$ (Note 2)		116	143	
		R <sub>DS</sub> (ON)	I <sub>D</sub> = 0.4 A, V <sub>GS</sub> = 2.5 V (Note 2)	> —	134	178	$m\Omega$
			I <sub>D</sub> = 0.2 A, V <sub>GS</sub> = 1.8 V (Note 2)	_	160	235	
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz	_	268	//	pF
Output capacitance		Coss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz	- (	44		pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz	(	34	<del>\</del> -	pF
Switching time	Turn-on time	t <sub>on</sub>	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 0.25 A,	(+	(9/)	) —	20
	Turn-off time	t <sub>off</sub>	$V_{GS} = 0$ to 2.5 V, $R_G = 4.7 \Omega$	<b>7</b> -\	16	_	ns
Drain-source forward voltage		V <sub>DSF</sub>	$I_D = -0.8 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 2)	<del>/</del> <del>)</del>	- 0.8	- 1.15	V

Note 2 : Pulse test

## Q2 Electrical Characteristics (Ta = 25°C)

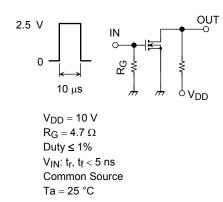
Characte	eristic	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$	- 20	_	_	V
		V (BR) DSX	$I_D = -1 \text{ mA}, V_{GS} = +8 \text{ V}$	- 12			v
Drain cutoff current		IDSS	$V_{DS} = -20 V, V_{GS} = 0$	_	_	- 10	μΑ
Gate leakage currer	nt // )	I <sub>GSS</sub>	$V_{GS} = \pm 8 V$ , $V_{DS} = 0$	_	_	± 1	μΑ
Gate threshold volta	ige	V <sub>th</sub>	$V_{DS} = -3 V$ , $I_{D} = -1 \text{ mA}$	- 0.3	_	- 1.0	V
Forward transfer ad	mittance	Y <sub>fs</sub>	$V_{DS} = -3 \text{ V}, I_D = -0.6 \text{ A}$ (Note 2)	1.5	2.5	_	S
Drain-source ON-resistance			$I_D = -0.6 \text{ A}, V_{GS} = -4.0 \text{ V}$ (Note 2)	_	175	234	
		R <sub>DS</sub> (ON)	$I_D = -0.4 \text{ A}, V_{GS} = -2.5 \text{ V}$ (Note 2)	_	230	306	mΩ
		4	$I_D = -0.1 \text{ A}, V_{GS} = -1.8 \text{ V}$ (Note 2)		300	460	
Input capacitance		Ciss	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		250		pF
Output capacitance		Coss	$V_{DS} = -\ 10\ V,\ V_{GS} = 0,\ f = 1\ MHz$	_	45	_	pF
Reverse transfer capacitance		Crss	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	35	_	pF
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = -10 \text{ V}, I_D = -0.25 \text{ A},$	_	12	_	20
	Turn-off time	t <sub>off</sub>	$V_{GS}$ = 0 to $-$ 2.5 V, $R_{G}$ = 4.7 $\Omega$	_	18	_	ns
Drain-source forward voltage		V <sub>DSF</sub>	$I_D = 0.8 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 2)	_	0.85	1.2	V

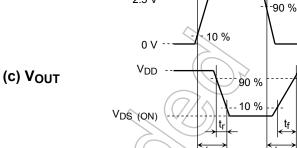
Note 2: Pulse test

## **Q1 Switching Time Test Circuit**

#### (a) Test Circuit

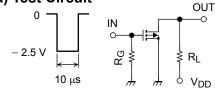






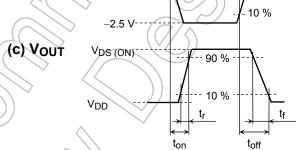
## **Q2 Switching Time Test Circuit**

#### (a) Test Circuit





 $V_{IN}$ :  $t_r$ ,  $t_f < 5$  ns Common Source Ta = 25 °C (b) V<sub>IN</sub>



90 %

#### Q1 Precaution

 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D$ = 1 mA for this product. For normal switching operation,  $V_{GS}$  (on) requires a higher voltage than  $V_{th}$ , and  $V_{GS}$  (off) requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows:  $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$ .)

Take this into consideration when using the device.

#### Q2 Precaution

 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D$ = - 1 mA for this product. For normal switching operation,  $V_{GS\ (on)}$  requires a higher voltage than  $V_{th}$ , and  $V_{GS\ (off)}$  requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows: V<sub>GS</sub> (off) < V<sub>th</sub> < V<sub>GS</sub> (on). )

Take this into consideration when using the device.

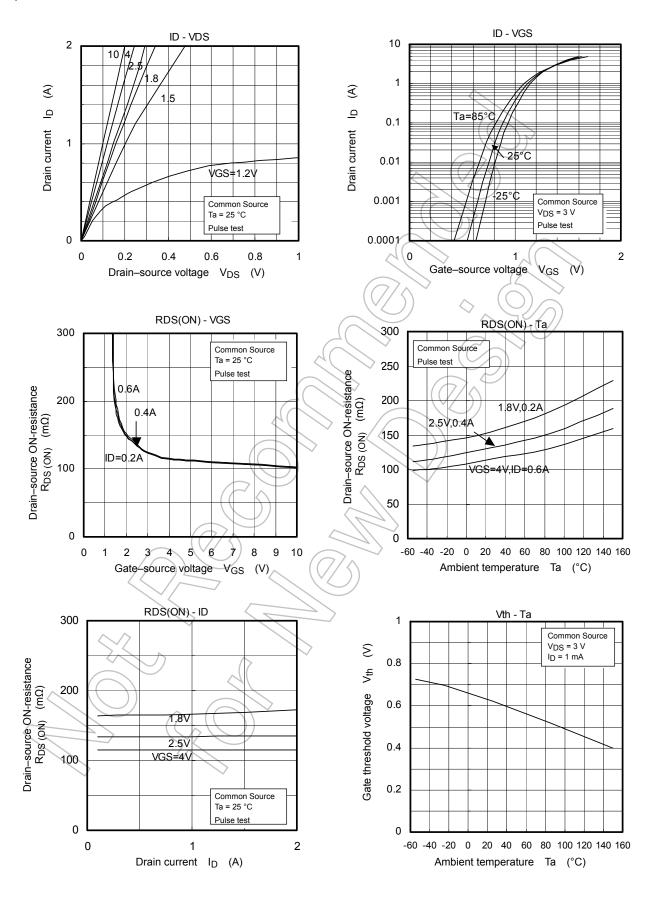
#### **Handling Precaution**

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance  $R_{th\ (ch-a)}$  and Power dissipation  $P_D$  vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

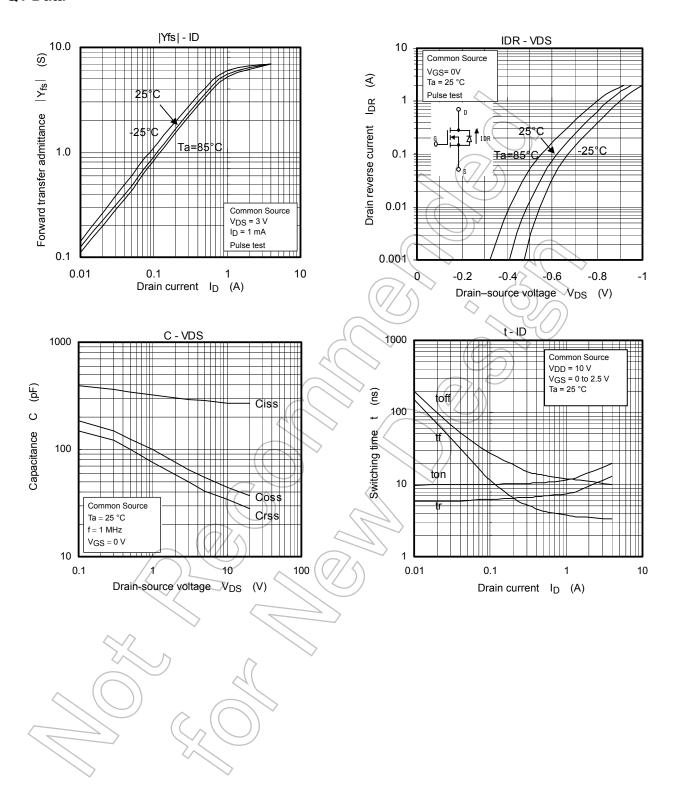
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#### Q1 Data

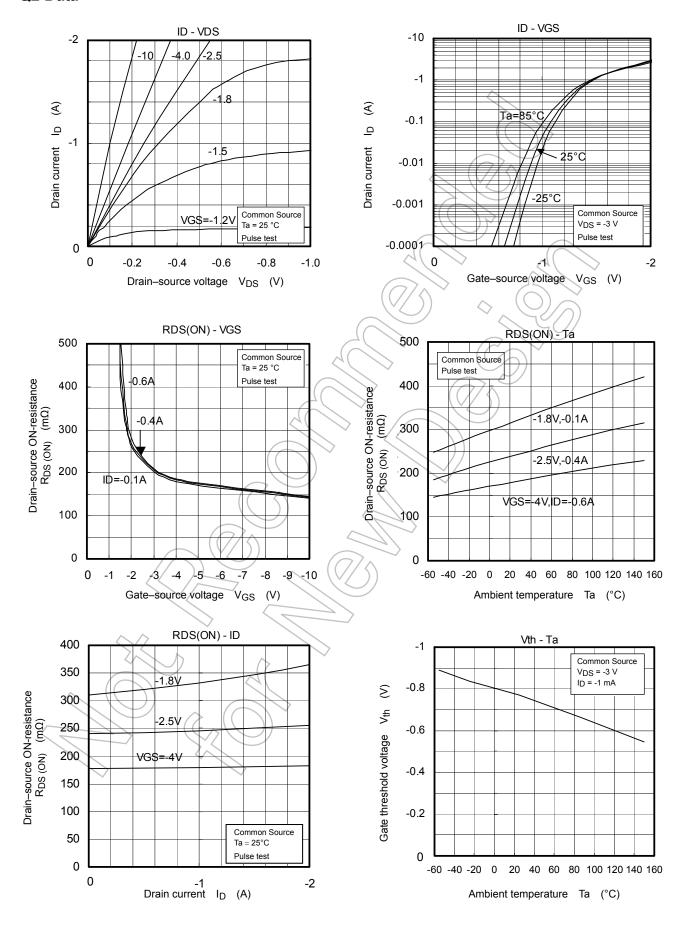


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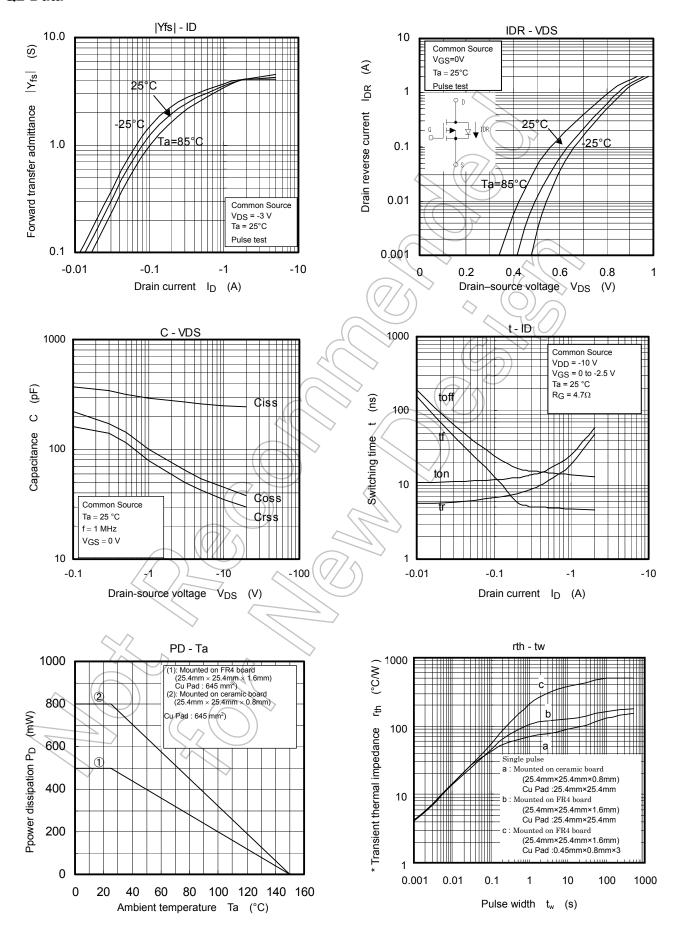
#### Q1 Data



#### Q2 Data



#### Q2 Data



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